# Silicon Epitaxial Planar Diode multicomp









SOD-123

#### Features:

- Fast Switching Speed: trr = 4ns (Typ.)
- · Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose Switching Applications
- · High Conductance
- · Available in Lead Free Version

## **Applications:**

· Surface mount fast switching diode

## **Maximum Ratings:**

Ratings at 25°C unless otherwise specified.

Characteristic	Symbol	Value	Unit
Non-Repetitive peak reverse voltage	VRM	100	V
Peak repetitive reverse voltage Working peak reverse voltage DC Reverse Voltage	Vrrm Vrwm Vr	75	V
RMS Reverse Voltage	VR(RMS)	53	V
Forward continuous current	Іғм	300	mA
Average rectified output current	lo	150	mA
Non-Repetitive peak forward surge current at t=1µs at t=1s	Ігѕм	2 1	А
Power dissipation	Pd	350	mW
Thermal resistance junction to ambient air	Reja	357	°C/W
Operating and storage temperature range	Тј, Тѕтс	-65 to+150	°C

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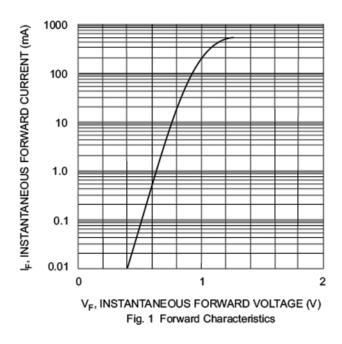
#### **Electrical Characteristics:**

Ratings at 25°C unless otherwise specified.

Characteristic	Symbol	Min.	Max.	Unit	Test Condition
Reverse breakdown voltage	V(BR)R	75	-	V	Ir = 1µA
Forward voltage	VF	-	0.715 0.855 1 1.25	V	IF = 1mA IF = 10mA IF = 50mA IF = 150mA
Reverse current	lr	-	1 25	μA nA	V <sub>R</sub> = 75V V <sub>R</sub> = 20V
Capacitance between terminals	Ст	-	2	pF	V <sub>R</sub> = 0, f = 1MHz
Reverse recovery time	trr	-	4	ns	I <sub>F</sub> = I <sub>R</sub> = 10mA, I <sub>rr</sub> = 0.1 × I <sub>R</sub> , R <sub>L</sub> = 100Ω

### **Typical Characteristics:**

T<sub>A</sub> = 25°C unless otherwise specified.



10,000 IR, LEAKAGE CURRENT (nA) 1000 100 10 200

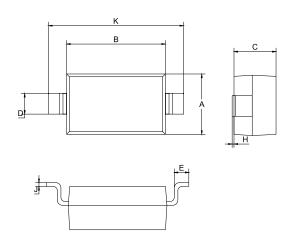
T<sub>i</sub>, JUNCTION TEMPERATURE (°C) Fig. 2 Leakage Current vs Junction Temperature

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#### **Package Outline:**

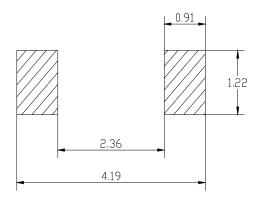
Plastic surface mounted package



SOD-123				
Dim.	Min.	Max.		
А	1.4	1.8		
В	2.55	2.85		
С	1.15 Typ.			
D	0.5	0.6		
E	0.3	0.4		
Н	0.02	0.1		
J	0.1 Typ.			
К	3.55	3.85		

**Dimensions: Millimetres** 

#### **Soldering Footprint:**



### **Package Information:**

Device	Package	Shipping
1N4148W-13-F	SOD-123	3,000 / Tape & Reel

#### **Part Number Table**

ĺ	Description	Part Number
	Silicon Epitaxial Planar Diode	1N4148W-13-F

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